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Publication Lists

A. International Journal:

- [1] Ya-Hsiang Tai, Bo-Ting Chen, Yu-Ju Kuo, Chun-Chien Tsai, Ko-Yu Chiang, Ying-Jyun Wei, and Huang-Chung Cheng, “A New Pixel Circuit for Driving Organic Light Emitting Diode with Low Temperature Polycrystalline Silicon Thin Film Transistors”, has been accepted by *IEEE/OSA Journal of Display Technology*, 2005.

B. International and Local Conferences:

- [1] Ya-Hsiang Tai, Bo-Ting Chen, Yu-Ju Kuo, Ying-Jyun Wei, Cheng-Chiu Pai, Chun-Chien Tsai, and Huang-Chung Cheng, “New Analog Buffer Circuit Using Low Temperature Polycrystalline Thin Film Transistors for Active Matrix Displays”, in *International Display Manufacturing Conference (IDMC)*, pp. 319-322, 2005 (*oral*)
- [2] Bo-Ting Chen, Yu-Ju Kuo, Cheng-Chiu Pai, Chun-Chien Tsai, Huang-Chung Cheng, and Ya-Hsiang Tai, “A New Pixel Circuit for Driving Organic Light Emitting Diodes with Low Temperature Polycrystalline Thin Film Transistors”, in *International Display Manufacturing Conference (IDMC)*, pp. 378-381, 2005 (*oral*)
- [3] Ya-Hsiang Tai, Bo-Ting Chen, Yu-Ju Kuo, Ying-Jyun Wei, Chun-Chien Tsai, Ko-Yu Chiang, and Huang-Chung Cheng, “New Pixel Circuits for Driving Organic Light Emitting Diodes with Low Temperature Polycrystalline Thin Film Transistors”, has been accepted by *International Display Workshops/Asia Display*, 2005

C. 專利申請

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